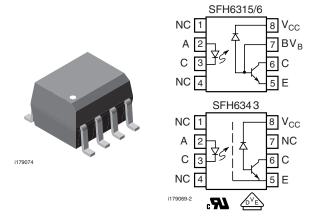
SFH6315T, SFH6316T, SFH6343T

Vishay Semiconductors

High Speed Optocoupler, 1 MBd, Transistor Output



DESCRIPTION

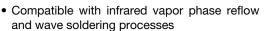
The SFH6315, SFH6316, SFH6343, high speed optocouplers, each consists of a GaAlAs infrared emitting diode, optically coupled with an integrated photo detector and a high speed transistor. The photo detector is junction isolated from the transistor to reduce miller capacitance effects. The open collector output function allows circuit designers to adjust the load conditions when interfacing with different logic systems such as TTL, CMOS, etc.

Because the SFH6343 has a faraday shield on the detector chip, it can also reject and minimize high input to output common mode transient voltages. There is no base connection, further reducing the potential electrical noise entering the package.

The SFH6315, SFH6316, SFH6343 are packaged in industry standard SOIC-8 packages and are suitable for surface mounting.

FEATURES

- Surface mountable
- Industry standard SOIC-8 footprint





- Isolation test voltage, 4000 V_{RMS}
- Very high common mode transient immunity: 15000 V/ μ s at V_{CM} = 1500 V guaranteed (SFH6343)
- High speed: 1 MBd
- TTL compatible
- Guaranteed AC and DC performance temperature: 0 °C to 70 °C
- Open collector output
- Pin compatible with agilent (HP) optocouplers
 - SFH6315T HCPL0500
 - SFH6316T HCPL0501
 - SFH6343T HCPL0453
- Material categorization: For definitions of compliance please see <u>www.vishay.com/doc?99912</u>

APPLICATIONS

- Line receivers
- Logic ground isolation
- · Analog signal ground isolation
- Replace pulse transformers

AGENCY APPROVALS

- UL1577, file no. E52744 system code Y
- cUL file no. E52744, equivalent to CSA bulletin 5A
- DIN EN 60747-5-5 (VDE 0884-5) available with option 1

ORDERING INFORMATIO	N		
S F H	6 3	# # T	SIOC-8
	PART NUMBER		6.1 mm
AGENCY CERTIFIED/PACKAGE		CTR (%)	
UL, cUL	≥ 5	≥ 15	NO BASE CONNECTION
SOIC-8	SFH6315T ⁽¹⁾	SFH6316T ⁽¹⁾	SFH6343T ⁽¹⁾

Note

(1) Also available in tubes; do not add T to end

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ABSOLUTE MAXIMUM RATINGS (T _{amb} = 25 °C, unless otherwise specified)								
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT				
INPUT								
Reverse voltage		V_R	3	V				
DC forward current		I _F	25	mA				
Surge forward current	t _p ≤ 1 μs, 300 pulses/s	I _{FSM}	1	Α				
Power dissipation	T _{amb} ≤ 70 °C	P _{diss}	45	mW				
OUTPUT								
Supply voltage		Vs	-0.5 to 30	V				
Output voltage		Vo	-0.5 to 25	V				
Output current		I _O	8	mA				
Power dissipation	T _{amb} ≤ 70 °C	P _{diss}	100	mW				
COUPLER								
Isolation test voltage between emitter and detector		V _{ISO}	4000	V _{RMS}				
Pollution degree (DIN VDE 0110)			2					
Comparative tracking index	DIN IEC 112/VDE 0303 part 1	CTI	175					
Storage temperature range		T _{stg}	-55 to +150	°C				
Ambient temperature range		T _{amb}	-55 to +100	°C				
Junction temperature		Tj	100	°C				
Soldering temperature (1)	max. 10 s, dip soldering distance to seating plane ≥ 1.5 mm		260	°C				

Notes

- Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not
 implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute
 maximum ratings for extended periods of the time can adversely affect reliability.
- (1) Refer to reflow profile for soldering conditions for surface mounted devices.

ELECTRICAL CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)								
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT	
INPUT								
Forward voltage	I _E = 16 mA, 25 °C		V_{F}		1.6	1.8	V	
i oi wai u voitage	IF = 10 IIIA, 25 G		V_{F}		1.6	1.9	V	
Reverse current	V _R = 3 V		I_{R}		0.5	10	μΑ	
Capacitance	$f = 1 MHz, V_F = 0 V$		C _{IN}		75		pF	
Temperature coefficient of forward voltage	I _F = 16 mA		$\Delta V_F/\Delta T_{amb}$		-1.7		mW/°C	
OUTPUT								
Logic low supply current	$I_F = 16 \text{ mA}, V_O = \text{open}, V_{CC} = 15 \text{ V}$		I _{CCL}		200		μΑ	
Logic high cumply current	$I_F = 0$ mA, $V_O = open$, $V_{CC} = 15$ V; 25 °C		I _{CCH}		0.001	1	μΑ	
Logic high supply current			I _{CCH}		0.001	2	μΑ	
	$I_F = 16 \text{ mA}, V_{CC} = 4.5 \text{ V}, I_O = 1.1 \text{ mA}, 25 ^{\circ}\text{C}$	SFH6315	V_{OL}		0.15	0.4	V	
	$I_F = 16 \text{ mA}, V_{CC} = 4.5 \text{ V}, I_O = 0.8 \text{ mA}$	SFH6315	V_{OL}		0.15	0.5	V	
Logic low output voltage	$I_F = 16 \text{ mA}, V_{CC} = 4.5 \text{ V}, I_O = 3 \text{ mA}, 25 ^{\circ}\text{C}$	SFH6316	V_{OL}		0.15	0.4	V	
Logic low output voltage	$I_F = 16 \text{ mA}, V_{CC} = 4.5 \text{ V}, I_O = 2.4 \text{ mA}$	SFH6343	V_{OL}		0.15	0.5	V	
	$I_F = 16 \text{ mA}, V_{CC} = 4.5 \text{ V}, I_O = 2.4 \text{ mA}$	SFH6316	V_{OL}		0.15	0.5	V	
	$I_F = 16 \text{ mA}, V_{CC} = 4.5 \text{ V}, I_O = 2.4 \text{ mA}$	SFH6343	V_{OL}		0.15	0.5	V	
	$I_F = 0 \text{ mA}, V_O = V_{CC} = 5.5 \text{ V}, 25 \text{ °C}$		I _{OH}		0.003	0.5	μΑ	
Logic high output current	$I_F = 0 \text{ mA}, V_O = V_{CC} = 15 \text{ V}, 25 \text{ °C}$		I _{OH}		0.01	1	μΑ	
	$I_F = 0 \text{ mA}, V_O = V_{CC} = 15 \text{ V}$		I _{OH}			50	μΑ	
COUPLER								
Capacitance (input to output) (1)	f = 1 MHz		C _{IO}		0.4		pF	

Notes

 Minimum and maximum values are testing requirements. Typical values are characteristics of the device and are the result of engineering evaluation. Typical values are for information only and are not part of the testing requirements.

(1) A 0.1 μF bypass capacitor connected between pins 5 and 8 is recommended.

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CURRENT TRANSFER RATIO									
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT		
	$V_{O} = 0.4 \text{ V}, I_{F} = 16 \text{ mA}, V_{CC} = 4.5 \text{ V}, 25 ^{\circ}\text{C}$	SFH6315	CTR	7	16	50	%		
	$V_{O} = 0.5 \text{ V}, I_{F} = 16 \text{ mA}, V_{CC} = 4.5 \text{ V}$	= 0.5 V, I _F = 16 mA, V _{CC} = 4.5 V SFH6315 CTR 5 17		%					
Current transfer ratio	$V_{O} = 0.4 \text{ V}, I_{F} = 16 \text{ mA}, V_{CC} = 4.5 \text{ V}, 25 ^{\circ}\text{C}$	SFH6316	CTR	19	35	50	%		
Current transfer fatto	$V_{O} = 0.4 \text{ V}, I_{F} = 16 \text{ mA}, V_{CC} = 4.5 \text{ V}, 25 ^{\circ}\text{C}$	SFH6343	CTR	19	35	50	%		
	$V_{O} = 0.5 \text{ V}, I_{F} = 16 \text{ mA}, V_{CC} = 4.5 \text{ V}$	SFH6343	CTR	15	36		%		
	$V_{O} = 0.5 \text{ V}, I_{F} = 16 \text{ mA}, V_{CC} = 4.5 \text{ V}$	SFH6316	CTR	15	36		%		

Note

Current transfer ratio in percent equals the ratio of output collector current (I_O) to the forward LED input current (I_F) times 100.
 A 0.1 μF bypass capacitor connected between pins 5 and 8 is recommended.

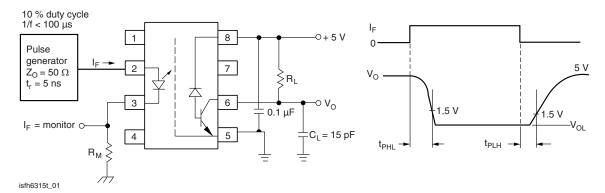


Fig. 1 - Test Circuit for Switching Times

SWITCHING CHARACTERISTICS								
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT	
	R _L = 4.1 KΩ	SFH6315	t _{PHL} (1)		0.5	1.5	μs	
Propagation delay time to logic		SFH6315	t _{PHL}		0.5	2	μs	
low at output (see fig. 1)	R _L = 1.9 KΩ	SFH6316	t _{PHL}		0.25	0.8	μs	
		SFH6343	t _{PHL}		0.25	1	μs	
Propagation delay time to logic high at output (see fig. 1)	R _L = 4.1 KΩ	SFH6315	t _{PLH} (1)		0.5	1.5	μs	
		SFH6315	t _{PLH}		0.5	2	μs	
	R _L = 1.9 KΩ	SFH6316	t _{PLH}		0.5	0.8	μs	
		SFH6343	t _{PLH}		0.5	1	μs	

Notes

- Over recommended temperature ($T_{amb} = 0$ °C to 70 °C), $V_{CC} = 5$ V, $I_F = 16$ mA unless otherwise specified. The 1.9 kW load represents 1 TTL unit load of 1.6 mA and the 5.6 kW pull-up resistor. The 4.1 kW load represents 1 LSTTL unit load of 0.36 mA and the 6.1 kW pull-up resistor.
- $^{(1)}$ T_{amb} = 25 °C, unless otherwise specified.

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COMMON MODE TRANSIENT IMMUNITY								
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT	
Common mode transient immunity at logic high level output (see fig. 2)	$\begin{aligned} \text{R}_\text{L} = 4.1 \text{ k}\Omega, \text{ I}_\text{F} = 0 \text{ mA}, \\ \text{V}_\text{CM} = 10 \text{ V}_\text{P-P} \end{aligned}$	SFH6315	CM _H		1		kV/μs	
	$R_L = 1.9 \text{ k}\Omega, I_F = 0 \text{ mA}, \\ V_{CM} = 1500 \text{ V}_{P-P}$	SFH6316	CM _H		1		kV/μs	
		SFH6343	CM _H	15	30		kV/μs	
Common mode transient immunity at logic low level output (see fig. 2)	$R_L = 4.1 \text{ k}\Omega, I_F = 16 \text{ mA}, \ V_{CM} = 10 \text{ V}_{P-P}$	SFH6315	CM _L		1		kV/μs	
	$R_L = 1.9 \text{ k}\Omega, I_F = 16 \text{ mA}, \ V_{CM} = 10 \text{ V}_{P-P}$	SFH6316	CM _L		1		kV/μs	
	$R_L = 1.9 \text{ k}\Omega, I_F = 16 \text{ mA}, \ V_{CM} = 1500 \text{ V}_{P-P}$	SFH6343	CM _L	15	30		kV/μs	

Note

Common mode transient immunity in a logic high level is the maximum tolerable (positive) dV_{CM}/dt on the leading edge of the common mode
pulse (V_{CM}) to assure that the output will remain in a logic high state (i.e., V_O > 2 V). Common mode transient immunity in a logic low level
the maximum tolerable (negative) dV_{CM}/dt on the trailing edge of the common mode pulse signal (V_{CM} to assure that the output will remain
in logic low state, i.e., V_O > 0.8 V).

The 1.9 k Ω load represents 1 TTL unit load of 1.6 mA and the 5.6 k Ω pull-up resistor.

The 4.1 $k\Omega$ load represents 1 LSTTL unit load of 0.36 mA and the 6.1 $k\Omega$ pull-up resistor.

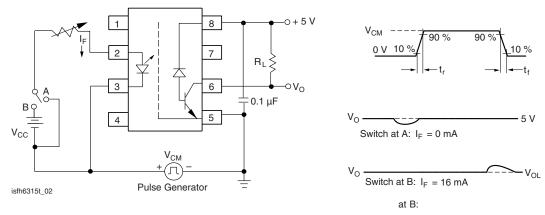


Fig. 2 - Test Circuit for Transient Immunity and Typical Waveforms

SAFETY AND INSULATION RATINGS								
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT		
Climatic Classification	according to IEC 68 part 1			55/100/21				
Comparative Tracking Index		CTI	175		399			
Maximum transient isolation voltage		V_{IOTM}	6000			V		
Maximum repetitive peak isolation voltage		V _{IORM}	560			V		
Output safety power		P _{SO}			350	mW		
Input safety current		I _{SI}			150	mA		
Input safety temperature		T _{SI}			165	°C		
Creepage distance			≥ 4			mm		
Clearance distance			≥ 4			mm		
Insulation resistance	$V_{IO} = 500 \text{ V}, T_{amb} = 25 \text{ °C}, R_{ISOL}$ (1)	R _{IO}	≥ 10 ¹²			Ω		
	$V_{IO} = 500 \text{ V}, T_{amb} = 100 ^{\circ}\text{C}, R_{ISOL} ^{(1)}$	R _{IO}	≥ 10 ¹¹			Ω		
Insulation thickness			0.2			mm		

Notes

- As per IEC 60747-5-5, §7.4.3.8.1, this optocoupler is suitable for "safe electrical insulation" only within the safety ratings. Compliance with
 the safety ratings shall be ensured by means of protective circuits.
- (1) Device considered a two-terminal device: pins 1, 2, 3, and 4 shorted together and pins 5, 6, 7, and 8 shorted together.

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TYPICAL CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)

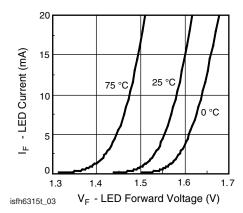


Fig. 3 - LED Forward Current vs. Forward Voltage

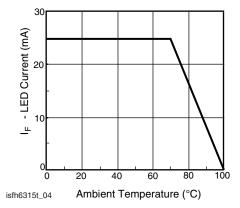


Fig. 4 - Permissible Forward LED Current vs. Temperature

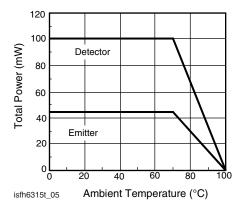


Fig. 5 - Permissible Power Dissipation vs. Temperature

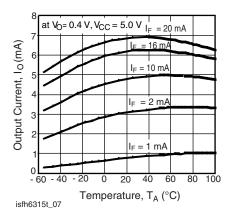


Fig. 6 - Output Current vs. Temperature

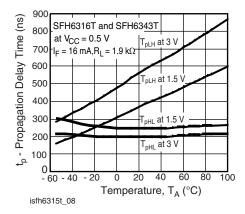


Fig. 7 - Propagation Delay vs. Temperature SFH6316T and SFH6343T

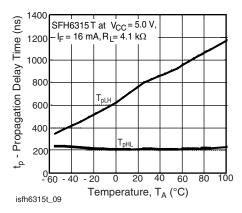


Fig. 8 - Propagation Delay vs. Temperature SFH6315T

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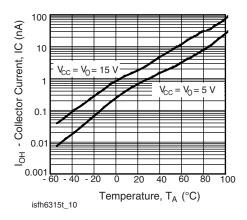


Fig. 9 - Logic High Output Current vs.Temperature

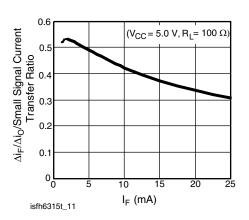
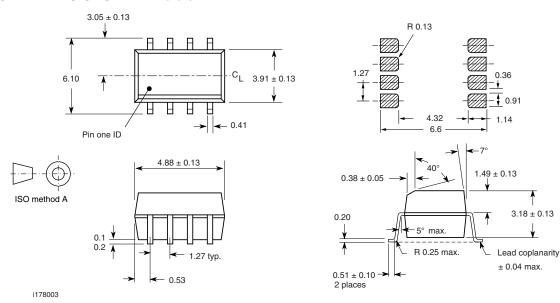


Fig. 10 - Small Signal Current Transfer Ratio vs. Input Current

PACKAGE DIMENSIONS in millimeters



PACKAGE MARKING (Example of SFH6315T)



Note

• Tape and reel suffix (T) is not part of the package marking.



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